

## 1200V 40A Trench and Field Stop IGBT

### DESCRIPTION :

- High ruggedness performance
- High speed switching
- Low collector to emitter saturation voltage
- Easy parallel switching capability
- Short circuit withstands time 10μs
- RoHS compliant.



### TYPICAL APPLICATIONS :

- Inverter
- Motor driver

TO-247

## IGBT

MAXIMUM RATINGS (Tvj=25°C unless otherwise specified)

Characteristic	Condition	Symbol	Value	Unit
Collector-Emitter Voltage		$V_{CES}$	1200	V
Continuous collector current	Tc=25°C Tc=100°C	$I_C$	80 40	A
Pulsed collector current	t <sub>p</sub> limited by Tvjmax	$I_{CM}$	160	A
Gate emitter voltage		$V_{GE}$	±20	V
Short circuit withstand time		t <sub>SC</sub>	10	us
Power dissipation	Tc=25°C Tc=100°C	$P_{tot}$	625 312	W
Operating junction temperature range		Tvj	-40~+175	°C
Storage temperature		T <sub>STG</sub>	-55~+150	°C

## THERMAL CHARACTERISTICS

Characteristic	Condition	Symbol	Max.	Unit
IGBT thermal resistance, junction - case		$R_{th(j-C)}$	0.24	K/W
Diode thermal resistance, junction - case		$R_{th(j-C)}$	0.49	K/W
Thermal resistance, junction - ambient		$R_{th(j-A)}$	40	K/W

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Collector-emitter cut-off current VCE=1200V, VGE=0V Tvj=25°C	$I_{CES}$			250	μA
Gate-emitter leakage current VCE=0V, VGE=±20V Tvj=25°C	$I_{GES}$			±100	nA
Gate-Emitter threshold voltage IC=1.0mA, VGE= VCE Tvj=25°C	$V_{GE(th)}$	5.0	6.0	7.0	V
Collector-Emitter saturation voltage VGE=15V, IC=40A Tvj=25°C VGE=15V, IC=40A Tvj=175°C	$V_{CE(SAT)}$		1.7 2.3		V
Input capacitance f=1MHz, VCE=30 V, VGE=0 V Tvj=25°C	$C_{ies}$		3210		pF
Output capacitance f=1MHz, VCE=30 V, VGE=0 V Tvj=25°C	$C_{oes}$		198		pF
Reverse transfer capacitance f=1MHz, VCE=30 V, VGE=0 V Tvj=25°C	$C_{res}$		29		pF
Gate charge IC = 40A, VGE = 15 V, VCC = 960V Tvj=25°C	$Q_G$		191		nC
Turn-on delay time IC=40A, VCC=600 V Tvj=25°C VGE=0/15 V, RG=10Ω Tvj=175°C (inductive load)	$t_{d(ON)}$		42 42		ns
Rise time IC=40A, VCC=600 V Tvj=25°C VGE=0/15 V, RG=10Ω Tvj=175°C (inductive load)	$t_r$		101 108		ns
Turn-off delay time IC=40A, VCC=600 V Tvj=25°C VGE=0/15 V, RG=10Ω Tvj=175°C (inductive load)	$t_{d(OFF)}$		266 290		ns
Fall time IC=40A, VCC=600 V Tvj=25°C VGE=0/15 V, RG=10Ω Tvj=175°C (inductive load)	$t_f$		70 127		ns
Turn-on energy IC=40A, VCC=600 V Tvj=25°C VGE=0/15 V, RG=10Ω Tvj=175°C (inductive load)	$E_{(ON)}$		4.0 6.0		mJ

Turn-off energy loss per pulse IC=40A, VCC=600 V      Tvj=25°C VGE=0/15 V, RG=10Ω      Tvj=175°C (inductive load)	E <sub>(OFF)</sub>		1.8 2.7		mJ
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## Diode

MAXIMUM RATINGS (Tvj=25°C unless otherwise specified)

Characteristic	Condition	Symbol	Value	Unit
Repetitive peak reverse voltage	Tvj=25°C	V <sub>RRM</sub>	1200	V
Continuous forward current	Tc=100°C	I <sub>F</sub>	40	A
Diode maximum current	t <sub>p</sub> limited by Tvj max	I <sub>FM</sub>	160	A

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Typ.	Max.	Unit
Forward voltage IF=40A, Tvj=25°C IF=40A, Tvj=175°C	V <sub>F</sub>		2.0 1.6		V
Reverse Recovered Time IF=40 A,      Tvj=25°C -diF/dt =750A/μs      Tvj=175°C VR=600 V	T <sub>rr</sub>		175 285		ns
Peak reverse recovery current IF=40 A,      Tvj=25°C -diF/dt =750A/μs      Tvj=175°C VR=600 V	I <sub>RRM</sub>		24 37		A
Reverse Recovered charge IF=40 A,      Tvj=25°C -diF/dt =750A/μs      Tvj=175°C VR=600 V	Q <sub>rr</sub>		2000 5500		nC

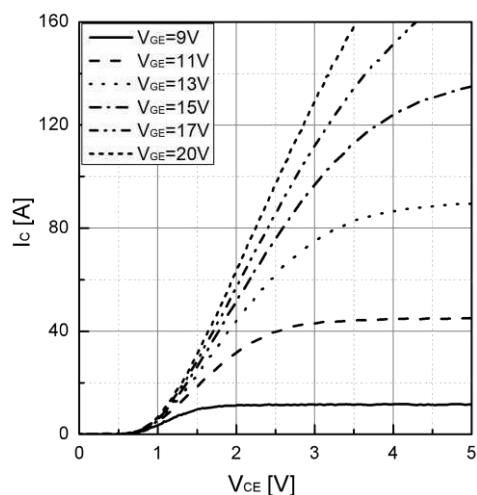


Figure 1. Typical output characteristics ( $T_{vj}=25^{\circ}\text{C}$ )

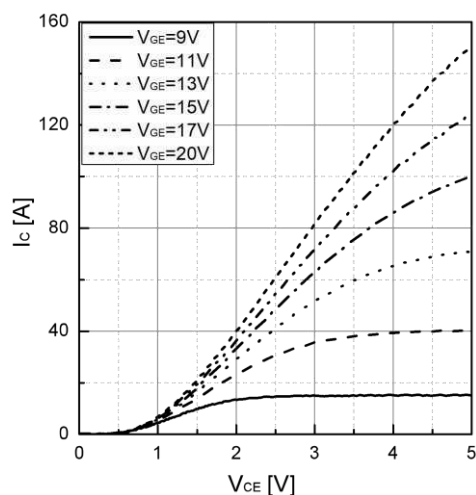


Figure 2. Typical output characteristics ( $T_{vj}=175^{\circ}\text{C}$ )

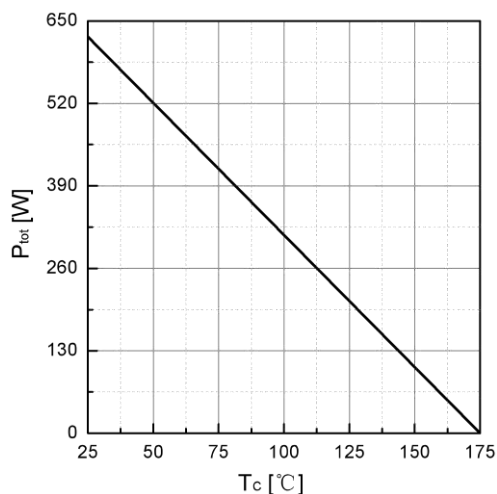


Figure 3. Power dissipation as a function of  $T_c$

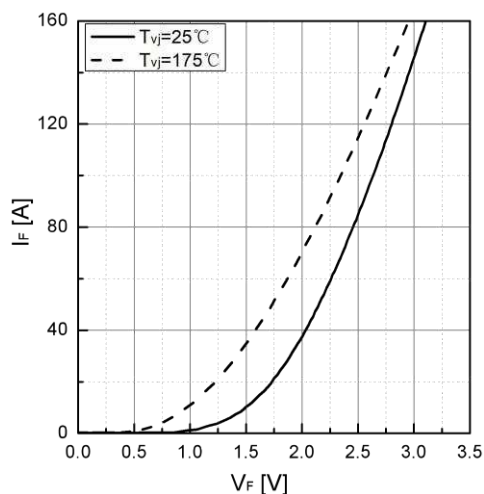


Figure 4. Typical  $I_F$  as a function of  $V_F$

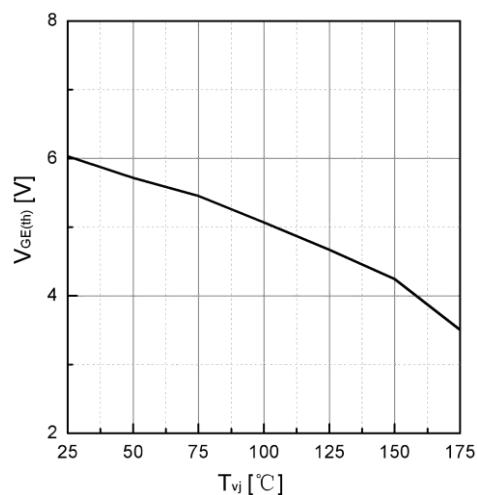


Figure 5. Typical  $V_{GE(th)}$  as a function of  $T_{vj}$  ( $I_c=1\text{mA}$ )

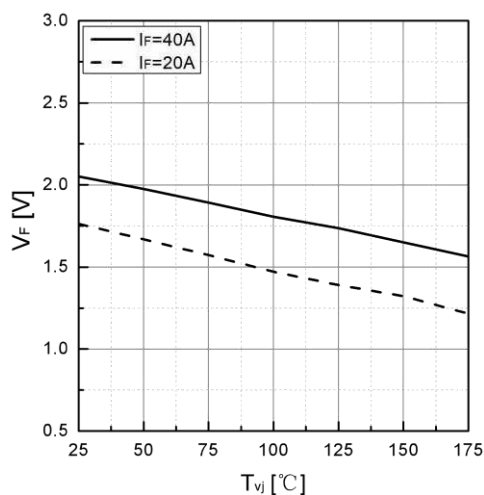


Figure 6. Typical  $V_F$  as a function of  $T_{vj}$

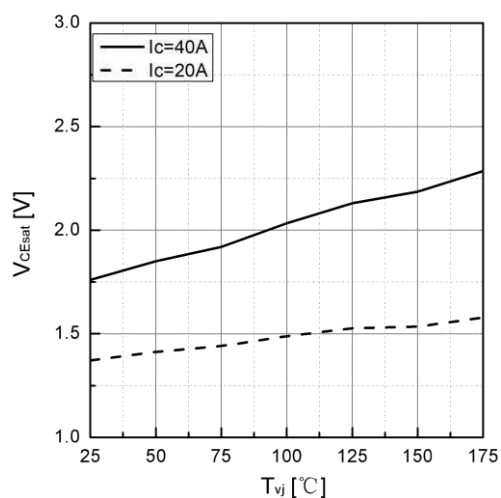


Figure 7. Typical VCEsat as a function of Tvj

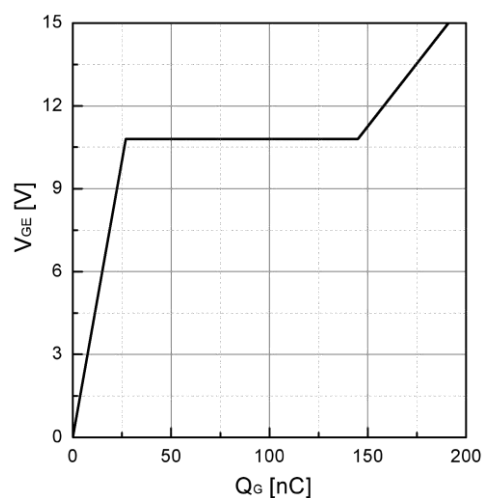


Figure 8. Typical Gate charge

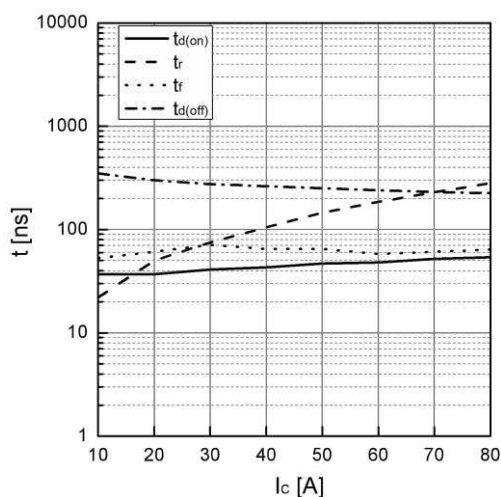


Figure 9. Typical switching times as a function of IC

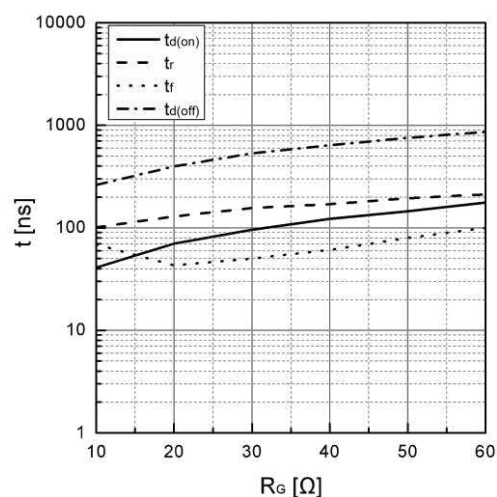


Figure 10. Typical switching times as a function of RG

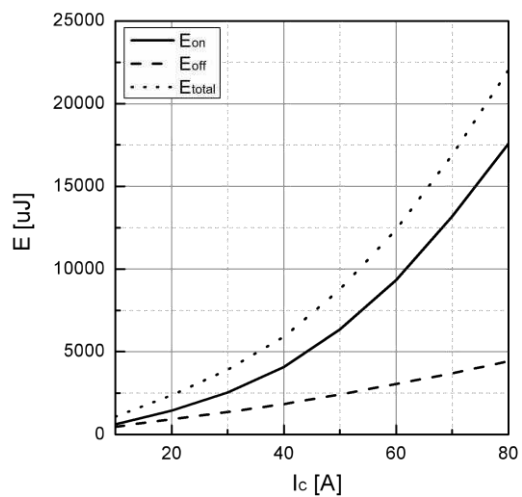


Figure 11. Typical switching energy losses as a function of IC

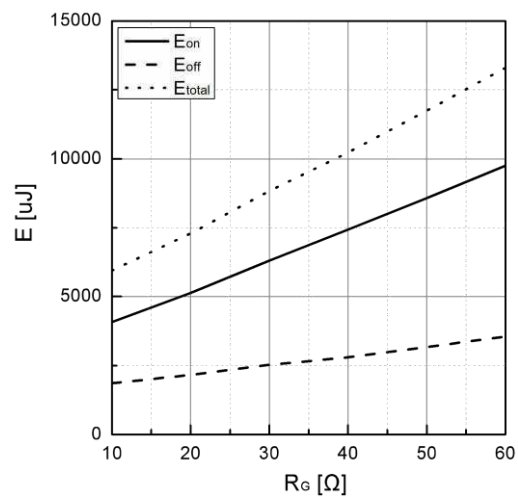


Figure 12. Typical switching energy losses as a function of RG

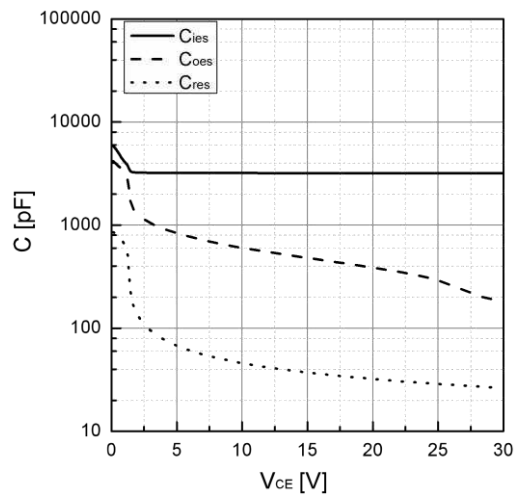


Figure 13. Typical capacitance as a function of VCE  
(f=1Mhz, VGE=0V)

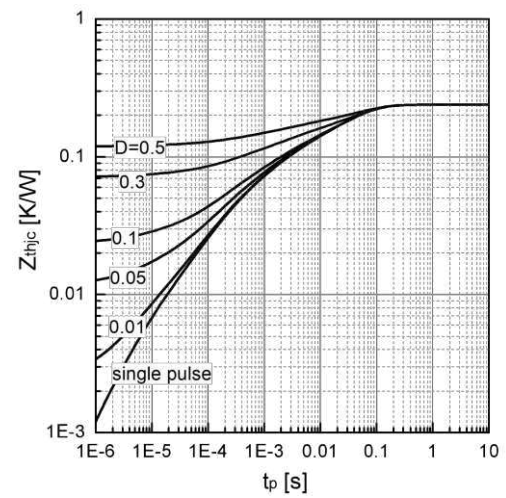


Figure 14. Transient thermal impedance, IGBT

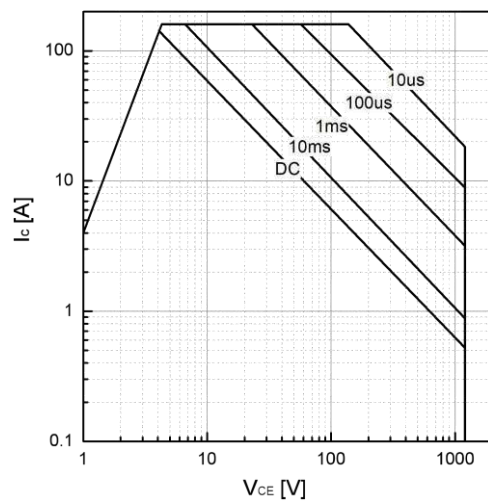
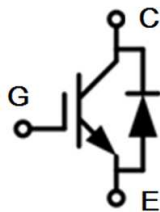
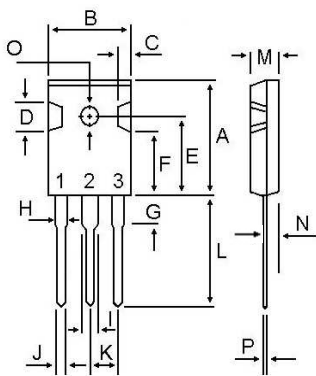


Figure 15. Safe operating area

- Circuit diagram



- Package outlines : Dimensions in (mm)



DIM	MILLIMETERS	
	MIN	MAX
A	20.80	21.80
B	15.38	16.20
C	1.90	2.70
D	5.10	6.10
E	14.50	15.50
F	11.20	13.20
G	3.75	4.35
H	1.90	2.30
I	2.90	3.30
J	1.00	1.40
K	5.26	5.66
L	19.50	20.50
M	4.68	5.36
N	2.30	2.60
O	3.45	3.85
P	0.48	0.72

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